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	Application No.	Applicant(s)
Notice of Allowability	10/765,156	: KOMATSUBARA, HIROTAKA
	Examiner	Art Unit
	Heather A. Doty	2813
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.		
1. X This communication is responsive to the amendment dated 5/31/05.		
2. 🔀 The allowed claim(s) is/are <u>5-15</u> .		
3. ⊠ The drawings filed on <u>28 January 2004</u> are accepted by the Examiner.		
 4. Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some* c) None of the: 1. Certified copies of the priority documents have been received. 		
2. Certified copies of the priority documents have been received in Application No		
3. Copies of the certified copies of the priority documents have been received in this national stage application from the		
International Bureau (PCT Rule 17.2(a)). * Certified copies not received:		
Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application. THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 5. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.		
6. ☐ CORRECTED DRAWINGS (as "replacement sheets") must be submitted. (a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached		
(a) ☐ including changes required by the Notice of Draitsperson's Patent Drawing Review (P 10-340) attached 1) ☐ hereto or 2) ☐ to Paper No./Mail Date		
(b) including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date		
Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).		
7. DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.		
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Attachment(s)	5. Notice of Informal P	Patent Application (PTO 152)
 Notice of References Cited (PTO-892) Dotice of Draftperson's Patent Drawing Review (PTO-948) 	6. ☐ Interview Summary	eatent Application (PTO-152)
	Paper No./Mail Da	te
 Information Disclosure Statements (PTO-1449 or PTO/SB/C Paper No./Mail Date 		
4. Examiner's Comment Regarding Requirement for Deposit		ent of Reasons for Allowance
of Biological Material	9.	
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An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

This application is in condition for allowance except for the presence of claims directed to an invention non-elected without traverse in the communication dated 1/21/05. Accordingly, the claims have been cancelled.

• Claims 1-4 are cancelled.

Allowable Subject Matter

Claims 5-15 are allowed.

The following is an examiner's statement of reasons for allowance:

Prior art does not teach or suggest, in combination with the other claimed limitations, a LOCOS method of isolation comprising the step of forming a metal oxide film for generating a fixed electric charge on the nitride film and on the silicon layer at least in an edge region of an element isolation region, whereby a threshold voltage of a parasitic transistor formed between the silicon layer and the field oxide film is raised and an influence of leakage current is reduced.

Prior art also does not teach or suggest, in combination with the other claimed limitations, a LOCOS method of isolation comprising implanting an impurity into a field oxide film at least in an edge region of the element isolation region to generate a fixed electric charge on the field oxide film, whereby a threshold voltage of a parasitic

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transistor formed between the silicon layer and the field oxide film is raised and an influence of leakage current is reduced. Cereda et al. (U.S. 5,696,399) teaches a LOCOS method including a step of implanting impurities through a field oxide into the underlying semiconductor, but does not teach, or in combination with relevant prior art suggest, generating a fixed electric charge on the field oxide film.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

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Conclusion

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Heather A. Doty, whose telephone number is 571-272-

8429. The examiner can normally be reached on M-F, 8:30 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Carl Whitehead, Jr., can be reached at 571-272-1702. The fax phone

number for the organization where this application or proceeding is assigned is 571-

273-8300.

Information regarding the status of an application may be obtained from the

Patent Application Information Retrieval (PAIR) system. Status information for

published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR only.

For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

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CRAIG A. THOMPSON PRIMARY EXAMINER

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